MOSFETs Silicon N-Channel MOS (DTMOSVI)

TK065Z65Z

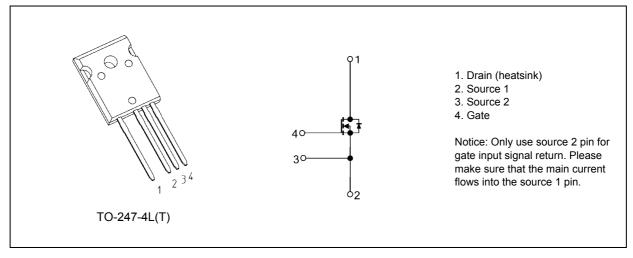
1. Applications

• Switching Power Supplies

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 0.054 \Omega$ (typ.)
- (2) High-speed switching properties with lower capacitance.
- (3) Enhancement mode: V_{th} = 3 to 4 V (V_{DS} = 10 V, I_D = 1.69 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25$ °C unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	650	V
Gate-source voltage			V _{GSS}	±30	1
Drain current (DC)		(Note 1)	I _D	38	Α
Drain current (pulsed)		(Note 1)	I _{DP}	152	1
Power dissipation	(T _c = 25 °C)		PD	270	W
Single-pulse avalanche energy		(Note 2)	E _{AS}	569	mJ
Single-pulse avalanche current			I _{AS}	9.5	Α
Reverse drain current (DC)		(Note 1)	I _{DR}	38	1
Reverse drain current (pulsed)		(Note 1)	I _{DRP}	152	1
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150]
Mounting torque			TOR	0.8	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 2019-03 2018-11-28

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	0.462	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	50	

Note 1: Ensure that the channel temperature does not exceed 150 °C. Note 2: V_{DD} = 90 V, T_{ch} = 25 °C (initial), L = 11.2 mH, I_{AS} = 9.5 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±30 V, V_{DS} = 0 V	_	_	±1	μA
Drain cut-off current	I _{DSS}	V_{DS} = 650 V, V_{GS} = 0 V	_	_	2	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	650	_	—	V
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 1.69 mA	3	_	4	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 19 A		0.054	0.065	Ω

6.2. Dynamic Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V_{DS} = 300 V, V_{GS} = 0 V, f = 100 kHz		3650	_	pF
Reverse transfer capacitance	C _{rss}	1		2.5	_	
Output capacitance	C _{oss}			83	_	
Effective output capacitance	C _{o(er)}	$V_{DS} = 0$ to 400 V, $V_{GS} = 0$ V		148		pF
Gate resistance	r _g	V _{DS} = OPEN , f = 1 MHz	_	3	_	Ω
Switching time (rise time)	tr	See Figure 6.2.1		25	_	ns
Switching time (turn-on time)	t _{on}		_	60	_	
Switching time (fall time)	t _f			4.2	_	
Switching time (turn-off time)	t _{off}	1		130	_	ns
MOSFET dv/dt ruggedness	dv/dt	$V_{DS} \le V_{(BR)DSS}, I_D \le 19 A$	120	_	_	V/ns

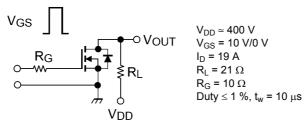


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS}$ = 10 V, I _D = 38 A		62	_	nC
Gate-source charge 1	Q _{gs1}		_	18	_	
Gate-drain charge	Q _{gd}		_	17	_	

6.4. Source-Drain Characteristics ($T_a = 25 \ ^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V_{DSF}	I _{DR} = 38 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	V _{DD} = 400 V,		350	_	ns
Reverse recovery charge	Q _{rr}	I _{DR} = 19 A, V _{GS} = 0 V -dI _{DR} /dt = 100 A/μs	—	6	_	μC
Peak reverse recovery current	l _{rr}		—	34	—	А
Diode dv/dt ruggedness	dv/dt	$V_{DD} \leq 400$ V, $I_{DR} \leq 19$ A, V_{GS} = 0 V	50	_	_	V/ns

7. Marking (Note)

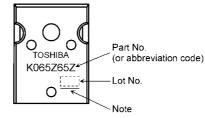


Fig. 7.1 Marking

 Note:
 A line under a Lot No. identifies the indication of product Labels.

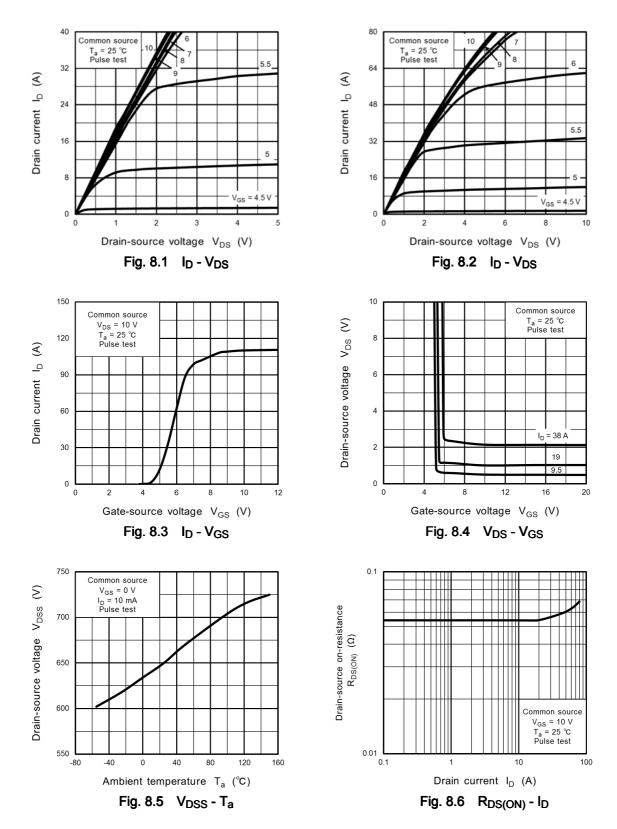
 Not underlined:
 [[Pb]]/INCLUDES > MCV

 Underlined:
 [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

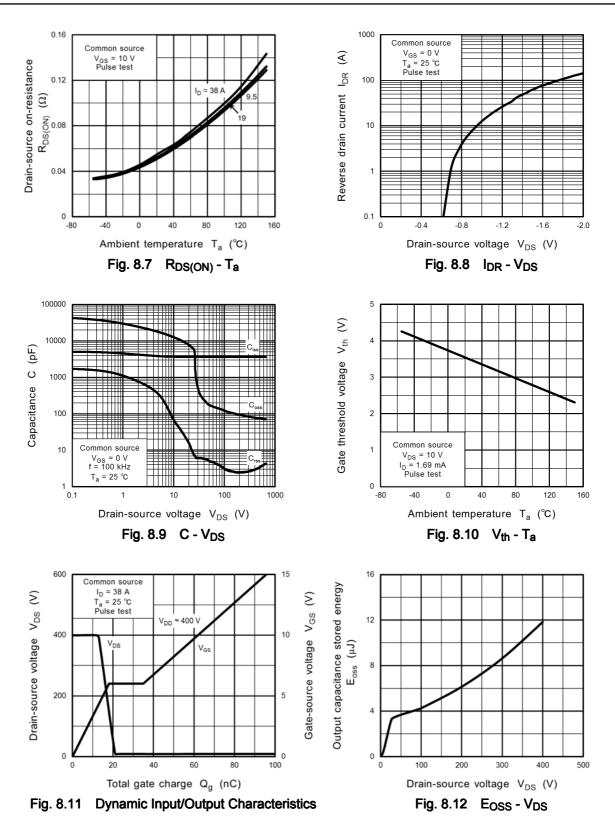
 Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

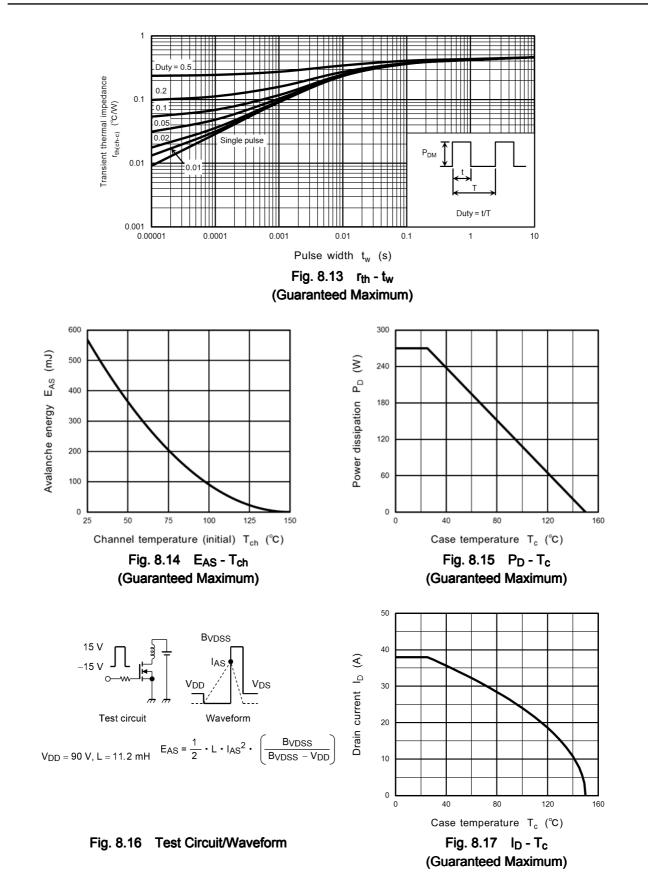
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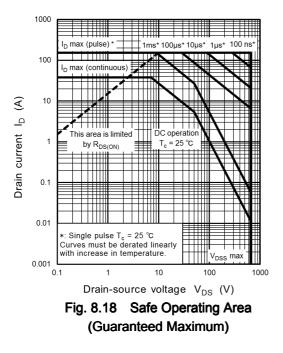
8. Characteristics Curves (Note)









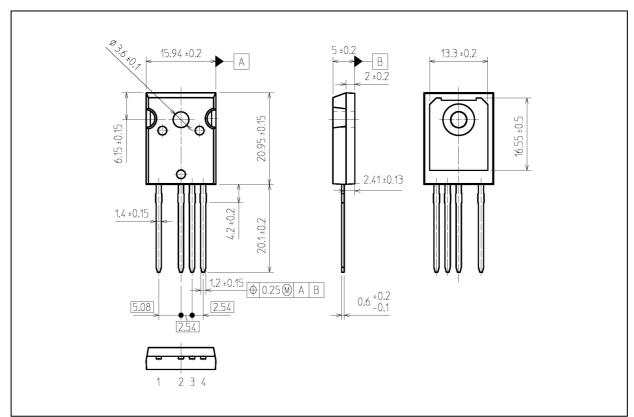


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

TK065Z65Z

Package Dimensions

Unit: mm



Weight: 6.35 g (typ.)

	Package Name(s)
TOSHIBA: 2-16M2A	
Nickname: TO-247-4L(T)	

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